



# CS1615M1A

## 主要参数 MAIN CHARACTERISTICS

I <sub>T(RMS)</sub>	16A
V <sub>DRM/V<sub>RRM</sub></sub>	600V/800V
I <sub>GT</sub>	1-15mA

### 用途

- 半交流开关
- 相位控制

### APPLICATIONS

- Half AC switching
- Phase control

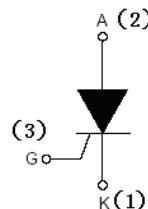
### 产品特性

- 玻璃钝化芯片，高可靠性和一致性
- 低通态电流和高浪涌电流能力
- 环保 RoHS 产品

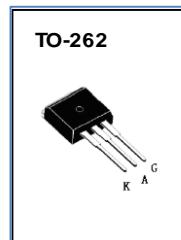
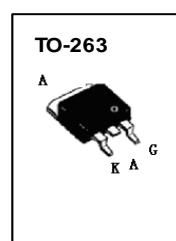
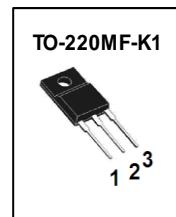
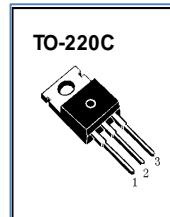
### FEATURES

- Glass-passivated mesa chip for reliability and uniform
- Low on-state voltage and High I<sub>TSM</sub>
- RoHS products

## 封装 Package



序号 Pin	引线名称 Description
1	阴极 K
2	阳极 A
3	门极 G



## 订货信息 ORDER MESSAGE

订 货 型 号 Order codes				印 记 Marking	封 装 Package
有卤-条管	无卤-条管	有卤-袋装	无卤-袋装		
Halogen-Tube	halogen-Free-Tube	Halogen-Bag	Halogen-Free- Bag		
CS1615M1A-C-B	CS1615M1A-C-BR	NA	NA	CS1615M 1A	TO-220C
有卤-条管	无卤-条管	有卤-袋装	无卤-袋装	CS1615M	TO-220MF



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CS1615M1A

Halogen-Tube	halogen-Free-Tube	Halogen-Bag	Halogen-Free-Bag	1A	-K1
CS1615M1A-F1-B	CS1615M1A-F1-BR	CS1615M1A-F1-C	CS1615M1A-F1-CR		
有卤-条管	无卤-条管	有卤-袋装	有卤-袋装	CS1615M 1A	TO-263
Halogen-Tube	halogen-Free-Tube	Halogen-Bag	Halogen-Free-Bag		
CS1615M1A-S-B	CS1615M1A-S-BR	CS1615M1A-S-C	CS1615M1A-S-CR		
有卤-条管	无卤-条管	有卤-袋装	有卤-袋装	CS1615M 1A	TO-262
Halogen-Tube	halogen-Free-Tube	Halogen-Bag	Halogen-Free-Bag		
CS1615M1A-B-B	CS1615M1A-B-BR	CS1615M1A-B-C	CS1615M1A-B-CR		
有卤-编带	无卤-编带	有卤-袋装	有卤-袋装	CS1615M 1A	DPAK
Halogen-Reel	Halogen-Free-Reel	Halogen-Bag	Halogen-Free-Bag		
CS1615M1A-R-A	CS1615M1A-R-AR	CS1615M1A-R-C	CS1615M1A-R-CR		
有卤-条管	无卤-条管	有卤-袋装	有卤-袋装	CS1615M 1A	IPAK
Halogen-Tube	halogen-Free-Tube	Halogen-Bag	Halogen-Free-Bag		
CS1615M1A-V-B	CS1615M1A-V-BR	CS1615M1A-V-C	CS1615M1A-V-CR		

## 绝对最大额定值 ABSOLUTE RATINGS (Tc=25°C)

项 目 Parameter	符 号 Symbol	数 值 Value	单 位 Unit
断态重复峰值电压 Repetitive peak off-state voltage	V <sub>DRM</sub>	600/800	V
反向重复峰值电压 Repetitive peak reverse voltage	V <sub>RDM</sub>	600/800	V
通态平均电流 Average on-state current ( half sine wave)	I <sub>T(AV)</sub>	10	A
通态方均根电流 On-state RMS current ( all conduction angles )	I <sub>T(RMS)</sub>	16	A
非重复浪涌峰值通态电流 Non-repetitive surge peak on-state current ( half sine wave ,t=10ms)	I <sub>TSM</sub>	200	A
I <sup>2</sup> t for fusing ( t=10ms)	I <sup>2</sup> t	200	A <sup>2</sup> s
门极峰值电流 Peak gate current	I <sub>GM</sub>	5	A
门极峰值电压 Peak gate voltage	V <sub>GM</sub>	5	V
反向门极峰值电压 Peak reverse gate voltage	V <sub>RGM</sub>	5	V
门极峰值功率 Peak gate power	P <sub>GM</sub>	20	W
门极平均功率 Average gate power ( over any 20ms period )	P <sub>G(AV)</sub>	0.5	W
存储温度 Storage temperature	T <sub>stg</sub>	-40~150	°C
操作结温 Operation junction temperature	T <sub>VJ</sub>	-40~150	°C



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静态特性 STATIC CHARACTERISTICS ( $T_c=25^\circ\text{C}$  unless otherwise stated)

项目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 min	典型 typ	最大 max	单位 Unit
断态峰值重复电流 Blocking Current	$I_{DRM}$	$V_{DM}=V_{DRM(\text{MAX})}$ , $T_j=150^\circ\text{C}$	-	-	4.0	mA
反向峰值重复电流 Reverse Current	$I_{RRM}$	$V_{RM}=V_{RRM(\text{MAX})}$ , $T_j=150^\circ\text{C}$	-	-	4.0	mA
峰值通态电压 Peak on-state voltage	$V_{TM}$	$I_{TM}=40\text{A}$	-	1.45	1.75	V
门极触发电流 Gate trigger current	$I_{GT}$	$V_{DM}=12\text{V}, I_T=0.1\text{A}$	1	5	15	mA
门极触发电压 Gate trigger voltage	$V_{GT}$	$V_{DM}=12\text{V}, I_T=0.1\text{A}$	-	0.8	1.5	V
维持电流 Holding current	$I_H$	$V_{DM}=12\text{V}, I_{GT}=0.1\text{A}$	-	-	40	mA
擎住电流 Latching current	$I_L$	$V_{DM}=12\text{V}, I_{GT}=0.1\text{A}$	-	-	60	mA

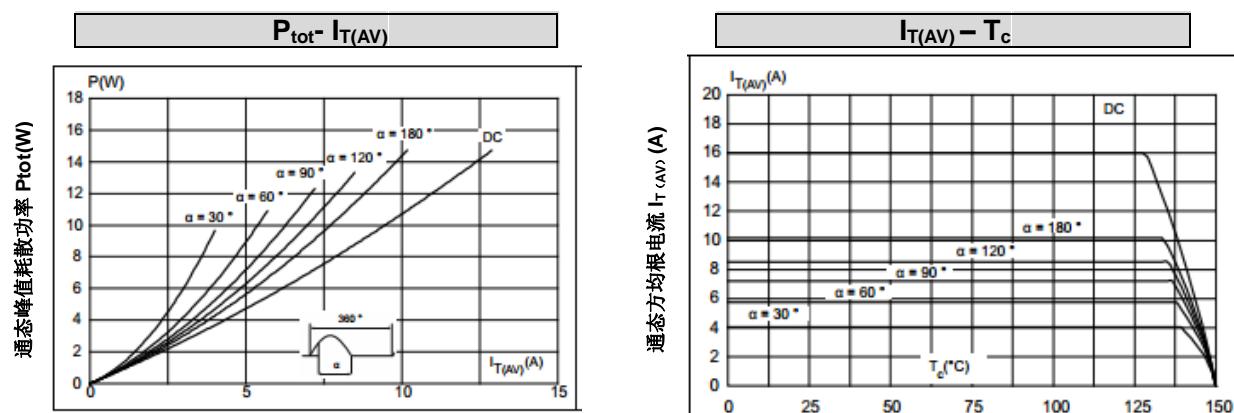
动态特性 DYNAMIC CHARACTERISTICS ( $T_c=25^\circ\text{C}$  unless otherwise stated)

项目 Parameter	符号 Symbol	测试条件 Tests conditions	最小 min	典型 typ	最大 max	单位 Unit
断态临界电压上升率 Critical rate of rise of off-state voltage	$dV/dt$	$V_{DM}=67\% V_{DRM(\text{MAX})}$ , $T_j=150^\circ\text{C}$	200		-	V/ $\mu$ s

## 热特性 THERMAL CHARACTERISTIC

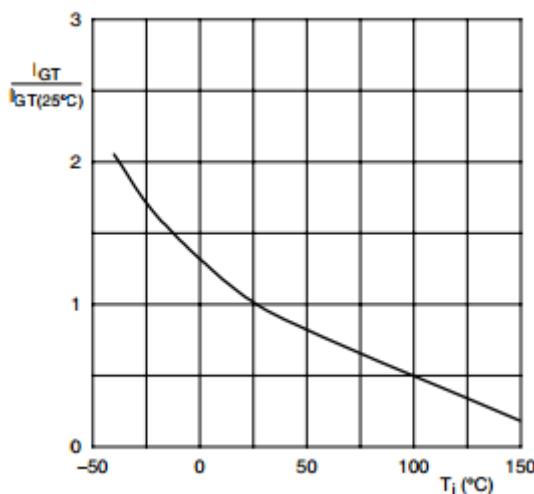
项目 Parameter	符号 Symbol	值 value	单位 Unit
结到管壳的热阻 Thermal resistance junction to case	$R_{th(j-c)}$	1.3 max	$^\circ\text{C}/\text{W}$
DPAK\IPAK	$R_{th(j-c)}$	1.8 max	
结到散热片的热阻 Thermal resistance junction to heatsink	$R_{th(j-hs)}$	4.5 max	
结到环境的热阻 Thermal resistance junction to ambient (half cycle)	$R_{th(j-a)}$	60 typ	

## 特征曲线 ELECTRICAL CHARACTERISTICS (curves)

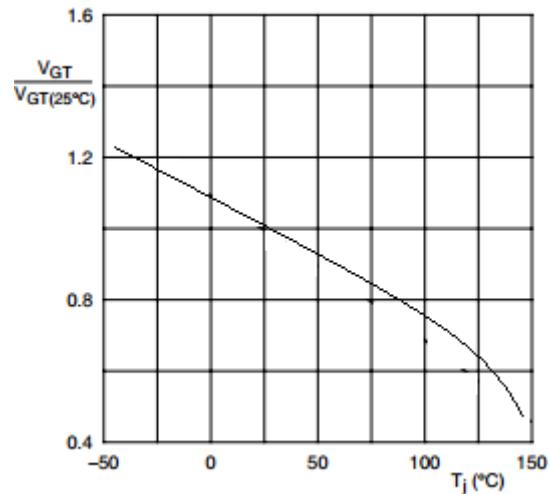


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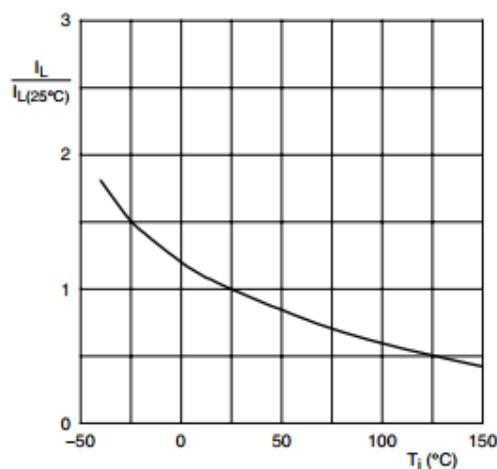
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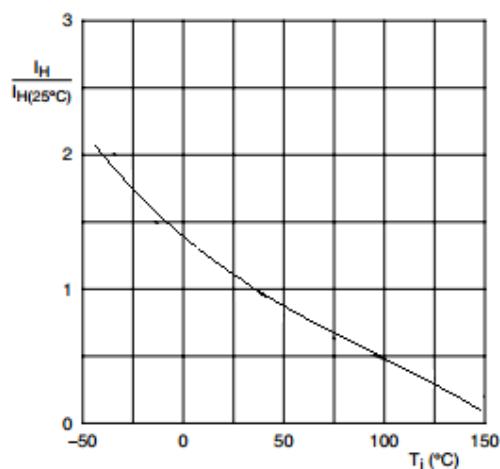
Normalized gate trigger current as a function of junction temperature



Normalized gate trigger voltage as a function of junction temperature



Normalized latching current as a function of junction temperature



Normalized holding current as a function of junction temperature

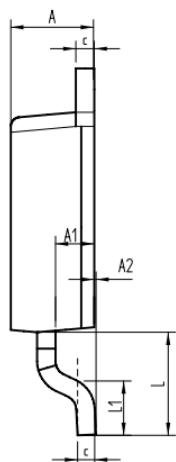
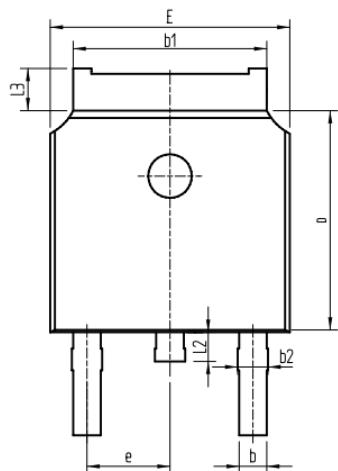


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## 外形尺寸 PACKAGE MECHANICAL DATA

DPAK

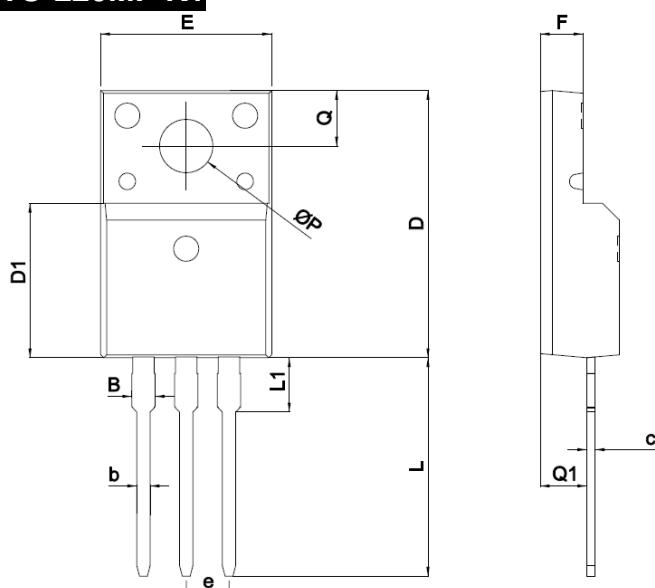
单位 Unit : mm



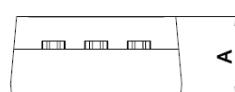
A	2.16-2.41
A1	0.97-1.17
A2	0.00-0.15
b	0.63-0.93
b1	5.13-5.53
b2	0.66-0.96
c	0.40-0.60
D	5.80-6.40
E	6.30-6.90
e	2.286 BSC
L	2.50-3.30
L1	1.20-1.80
L2	0.60-1.00
L3	0.85-1.30

TO-220MF-K1

单位 Unit : mm

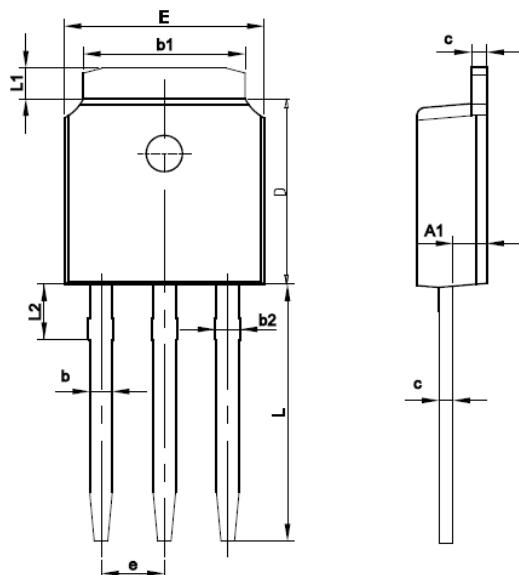


SYMBOL	mm	
	MIN	MAX
A	4.5	4.9
B	1.22	1.47
b	0.7	0.9
c	0.45	0.60
D	15.6	16.1
D1	9.0	9.3
e	2.54TYPE	
E	9.9	10.4
F	2.3	2.8
L	12.6	13.3
L1	3.1	3.4
Q	3.2	3.4
Q1	2.6	2.9
QP	3.0	3.5

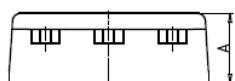


IPAK

单位 Unit : mm



SYMBOL	MM	
	MIN	MAX
A	2.10	2.50
A1	0.87	1.27
b	0.63	0.93
b1	5.13	5.53
b2	0.67	1.00
c	0.40	0.60
D	5.80	6.40
E	6.30	6.90
L	9.10	9.70
e	2.286BSC	
L1	0.82	1.22
L2	0.90	1.20

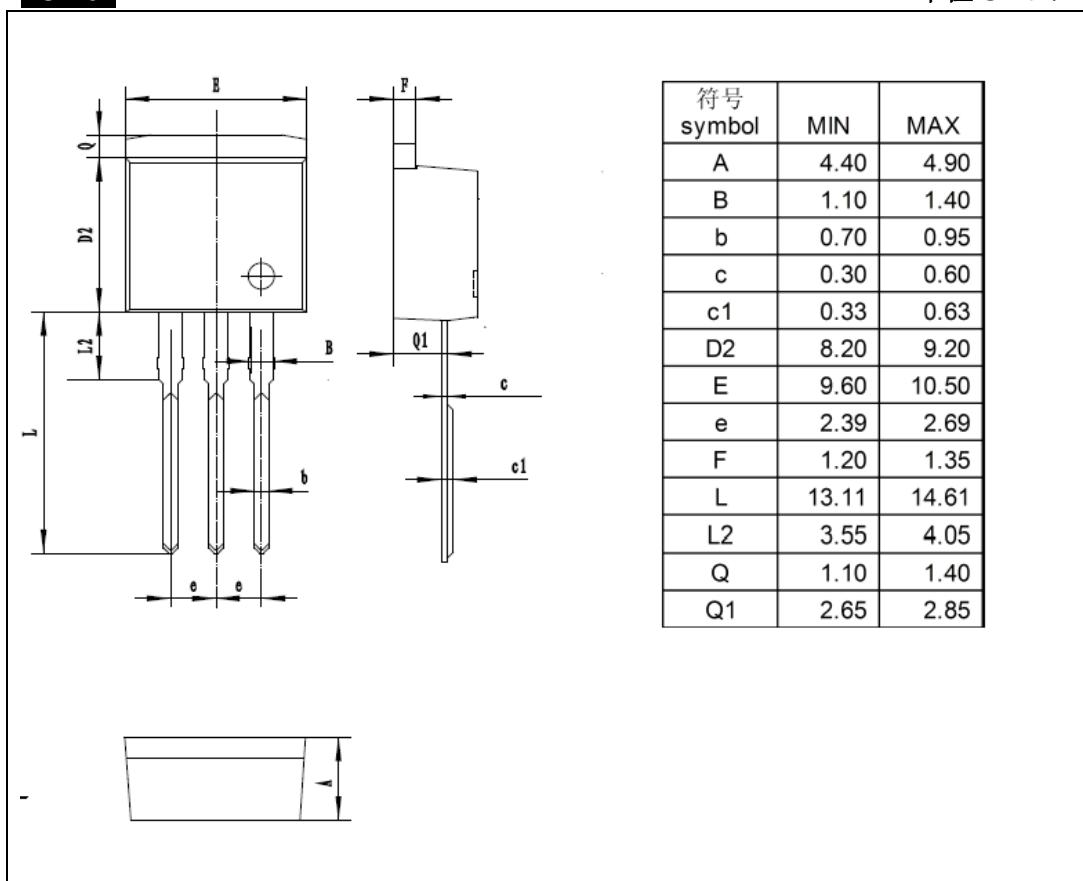




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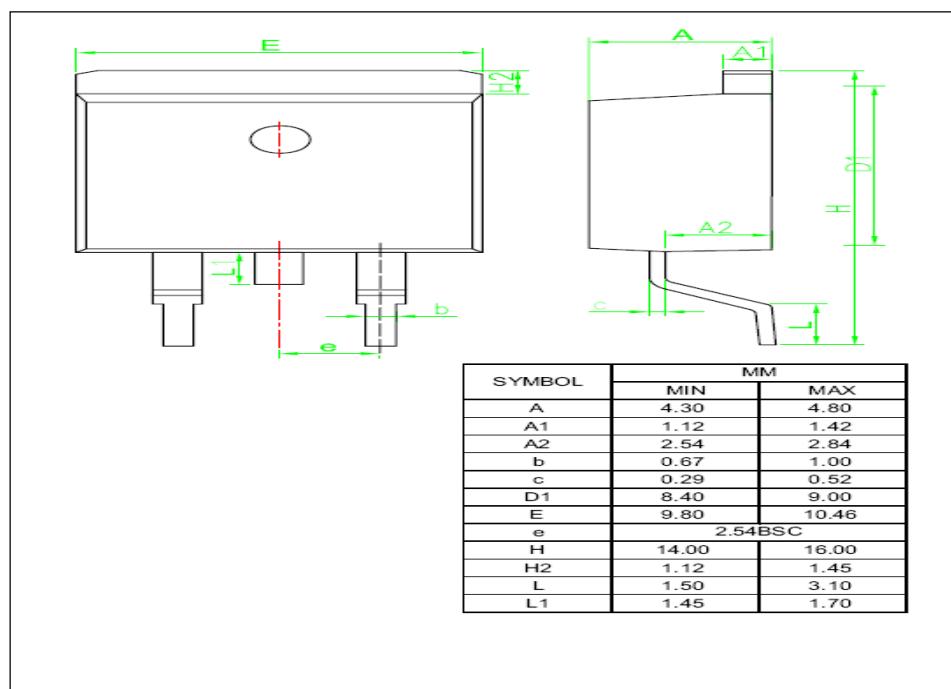
TO-262

单位 Unit : mm



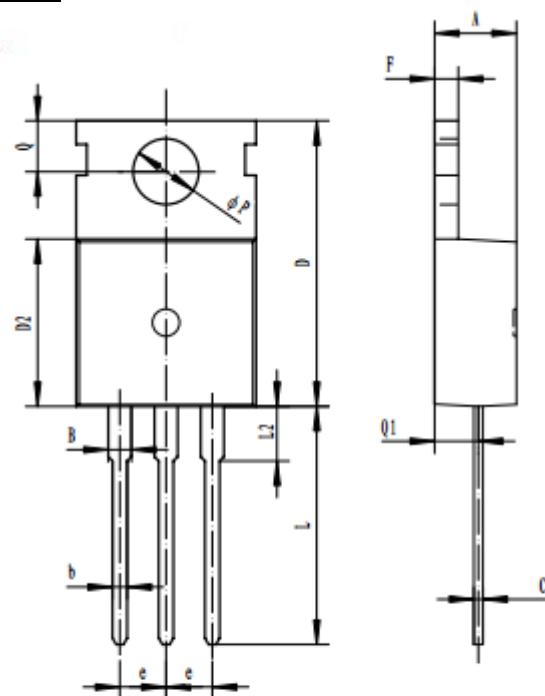
TO-263

单位 Unit : mm



TO-220C

单位 Unit : mm



A	4.30-4.70
B	1.22-1.40
b	0.70-0.95
c	0.40-0.65
D	15.2-16.2
D2	9.00-9.40
E	9.70-10.10
e	2.39-2.69
F	1.25-1.40
L	12.60-13.60
L2	2.80-3.20
Q	2.60-3.00
Q1	2.20-2.60
P	3.50-3.80



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